# NSN 5962-01-365-5648

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# Maximum Power Dissipation Rating:

2.0 watts

# **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

### Features Provided:

Burn in and electrostatic sensitive and programmed and monolithic and ultraviolet erasable

#### Inclosure Material:

Ceramic

# Inclosure Configuration:

Dual-in-line

#### Output Logic Form:

Metal oxide-semiconductor logic

# Input Circuit Pattern:

32 input

# Case Outline Source And Designator:

D-5 mil-m-38510

# **Terminal Surface Treatment:**

Solder

#### Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

#### Memory Device Type:

Eprom

#### Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

#### **Terminal Type And Quantity:**

40 printed circuit

#### Shelf Life:

N/a

#### Unit Of Measure:

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# Demilitarization:

Yes - demil/mli

Fiig:

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